



AF/2813

Serial No. 09/902,429
Attorney Docket No. F0588
Firm Reference No. AMDSP0480US

Reply to Office Action Dated December 30, 2003
Reply Dated February 11, 2004

CERTIFICATE OF MAILING OR FACSIMILE TRANSMISSION UNDER 37 CFR 1.8(a)

I hereby certify that this paper (along with any paper referred to as being attached or enclosed) is
X being deposited with the United States Postal Service with sufficient postage for first class mail in an envelope addressed to
the Commissioner for Patents address below.

being transmitted via facsimile to (703) 872-9306 at the U.S. Patent and Trademark Office to the Attention of Examiner
Laura M. Schillinger.

Andrew Romero
Andrew Romero

February 11, 2004
Date

RECEIVED

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE FEB 23 2004

In re patent application of:

Applicant: Qi Xiang et al.

Art Unit: 2813

Serial No: 09/902,429

Examiner: Laura M. Schillinger

Filing Date: 07/10/2001

Confirmation No: 7718

Title: **SILICON ON INSULATOR FIELD EFFECT TRANSISTOR WITH
HETEROJUNCTION GATE**

Mail Stop AF: Expedited Procedure
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Mail Stop AF
EXPEDITED
PROCEDURE

REPLY TO OFFICE ACTION DATED DECEMBER 30, 2003

Dear Sir:

Favorable reconsideration of the above-identified application is respectfully requested in view of the following amendments and comments. It is believed that the amendments contained herein raise no new issues, do not require an additional search and place the application in a better condition for allowance and/or appeal. Accordingly, entry of the amendment is considered proper.

Amendments in the Drawings begin on page 2 of this paper and include four attached replacement sheets.

Amendments in the Specification begin on page 3 of this paper.

Amendments in the Claims begin on page 6 of this paper.

Remarks begin on page 10 of this paper.